SCDS044I - DECEMBER 1997 - REVISED OCTOBER 2003

- **Member of the Texas Instruments** Widebus™ Family
- 4- Ω Switch Connection Between Two Ports
- Rail-to-Rail Switching on Data I/O Ports
- Ioff Supports Partial-Power-Down Mode Operation
- **Break-Before-Make Feature**
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

description/ordering information

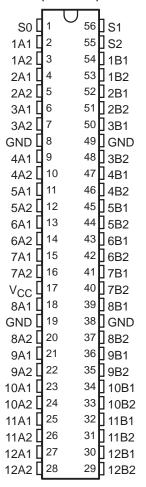
The SN74CBTLV16212 provides 24 bits of high-speed bus switching or exchanging. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device operates as a 24-bit bus switch or a 12-bit bus exchanger, which provides data exchanging between the four signal ports via the data-select (S0, S1, S2) terminals.

This device is fully specified partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

The SN74CBTLV16212 is specified by the break-before-make feature to have no through current when switching between B ports.

DGG, DGV, OR DL PACKAGE (TOP VIEW)



ORDERING INFORMATION

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	CCOD DI	Tube	SN74CBTLV16212DL	CDTI VACOAO		
-40°C to 85°C	SSOP – DL	Tape and reel	SN74CBTLV16212DLR	CBTLV16212		
-40 C to 65 C	TSSOP - DGG	Tape and reel	SN74CBTLV16212GR	CBTLV16212		
	TVSOP - DGV	Tape and reel	SN74CBTLV16212VR	CN212		

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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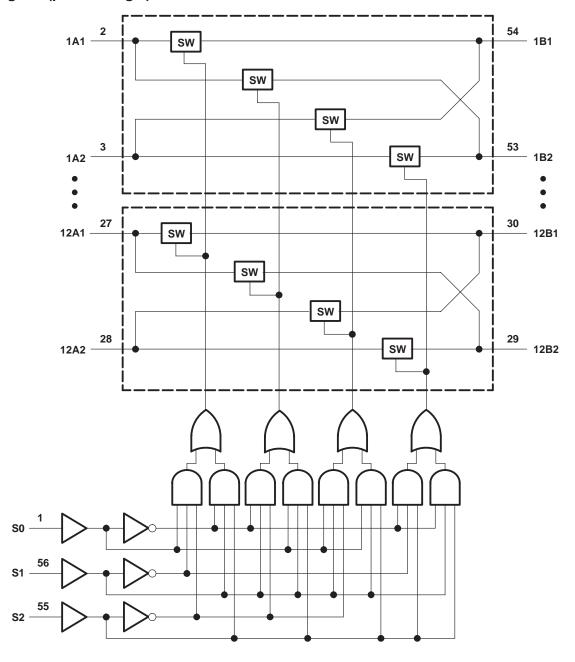
SN74CBTLV16212 LOW-VOLTAGE 24-BIT FET BUS-EXCHANGE SWITCH

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FUNCTION TABLE

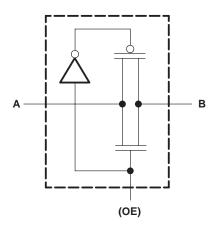
	INPUTS		INPUTS/	OUTPUTS	FUNCTION
S2	S1	S0	A1	A2	FUNCTION
L	L	L	Z	Z	Disconnect
L	L	Н	B1	Z	A1 port = B1 port
L	Н	L	B2	Z	A1 port = B2 port
L	Н	Н	Z	B1	A2 port = B1 port
Н	L	L	Z	B2	A2 port = B2 port
Н	L	Н	Z	Z	Disconnect
н	Н	L	B1	B2	A1 port = B1 port A2 port = B2 port
Н	Н	Н	B2	B1	A1 port = B2 port A2 port = B1 port

logic diagram (positive logic)



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simplified schematic, each FET switch



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}		-0.5 V to	4.6 V
Input voltage range, V _I (see Note 1)			
Continuous channel current			
Input clamp current, I _{IK} (V _I < 0)		–5	0 mA
Package thermal impedance, θ _{JA} (see Note 2):	DGG package	64	°C/W
	DGV package	48	°C/W
	DL package	56	°C/W
Storage temperature range, T _{stg}		-65°C to 1	50°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

		MIN	MAX	UNIT
VCC	Supply voltage	2.3	3.6	V
.,	$V_{CC} = 2.3 \text{ V}$ to 2.7 V	1.7		W
VIH	High-level control input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		v
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
VIL	Low-level control input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V
TA	Operating free-air temperature	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

SN74CBTLV16212 LOW-VOLTAGE 24-BIT FET BUS-EXCHANGE SWITCH

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAI	RAMETER	TEST CONDITIONS				TYP [†]	MAX	UNIT
VIK		V _{CC} = 3 V,	I _I = -18 mA				-1.2	V
Ц		V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND				±1	μΑ
l _{off}		$V_{CC} = 0$,	V _I or V _O = 0 to 3.6 V				10	μΑ
Icc		V _{CC} = 3.6 V,	I _O = 0,	V _I = V _{CC} or GND			10	μΑ
∆lcc [‡]	Control inputs	V _{CC} = 3.6 V,	One input at 3 V,	Other inputs at V _{CC} or GND			300	μΑ
Ci	Control inputs	V _I = 3 V or 0				5		pF
C _{io(OFF}	=)	$V_0 = 3 \text{ V or } 0,$	S_1 , S_2 , and $S_3 = GN$	D		8		pF
			, , ,	I _I = 64 mA		5	8	
		$V_{CC} = 2.3 \text{ V},$ TYP at $V_{CC} = 2.5 \text{ V}$	V _I = 0	I _I = 24 mA		5	8	
. 8		111 at VCC = 2.5 V	V _I = 1.7 V,	I _I = 15 mA		27	40	0
r _{on} §				I _I = 64 mA		5	7	Ω
		VCC = 3 V	V _I = 0	I _I = 24 mA		5	7	
			V _I = 2.4 V,	I _I = 15 mA		10	15	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

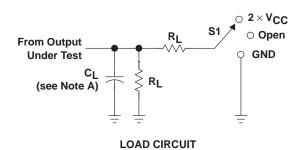
PARAMETER	FROM	TO	V _{CC} =	2.5 V 2 V	V _{CC} =		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
$t_{pd}\P$	A or B	B or A		0.15		0.25	ns
^t pd	S	B or A	3	11.1	3	8.8	ns
t _{en}	S	A or B	3	10.9	3	8.6	ns
^t dis	S	A or B	1	8.7	2	8.8	ns

The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

[‡] This is the increase in supply current for each input that is at the specified voltage level, rather than V_{CC} or GND.

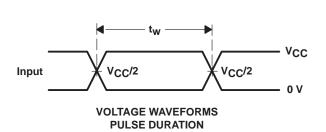
[§] Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

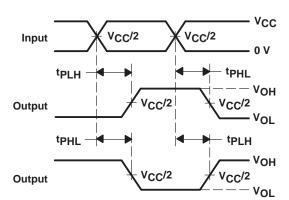
PARAMETER MEASUREMENT INFORMATION



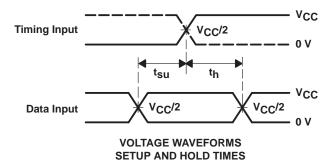
TEST	S1
tPLH/tPHL	Open
t _{PLZ} /t _{PZL}	2×V _{CC}
tPHZ/tPZH	GND

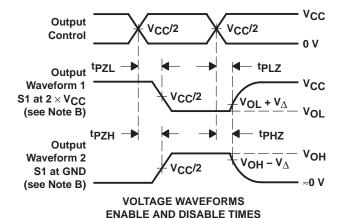
VCC	CL	RL	$v_{\scriptscriptstyle\Delta}$
2.5 V ±0.2 V	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	50 pF	500 Ω	0.3 V





VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS





LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. tpZL and tpZH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(0)
SN74CBTLV16212DL	Active	Production	SSOP (DL) 56	20 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212DL.B	Active	Production	SSOP (DL) 56	20 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212DLR	Active	Production	SSOP (DL) 56	1000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212DLR.B	Active	Production	SSOP (DL) 56	1000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212GR	Active	Production	TSSOP (DGG) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212GR.B	Active	Production	TSSOP (DGG) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212GRG4	Active	Production	TSSOP (DGG) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212GRG4.B	Active	Production	TSSOP (DGG) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV16212
SN74CBTLV16212VR	Active	Production	TVSOP (DGV) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CN212
SN74CBTLV16212VR.B	Active	Production	TVSOP (DGV) 56	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CN212

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBTLV16212DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
SN74CBTLV16212GR	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74CBTLV16212GRG4	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74CBTLV16212VR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1

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*All dimensions are nominal

7 til dillionoro dio monimiai							
Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBTLV16212DLR	SSOP	DL	56	1000	356.0	356.0	53.0
SN74CBTLV16212GR	TSSOP	DGG	56	2000	356.0	356.0	45.0
SN74CBTLV16212GRG4	TSSOP	DGG	56	2000	356.0	356.0	45.0
SN74CBTLV16212VR	TVSOP	DGV	56	2000	356.0	356.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74CBTLV16212DL	DL	SSOP	56	20	473.7	14.24	5110	7.87
SN74CBTLV16212DL.B	DL	SSOP	56	20	473.7	14.24	5110	7.87

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



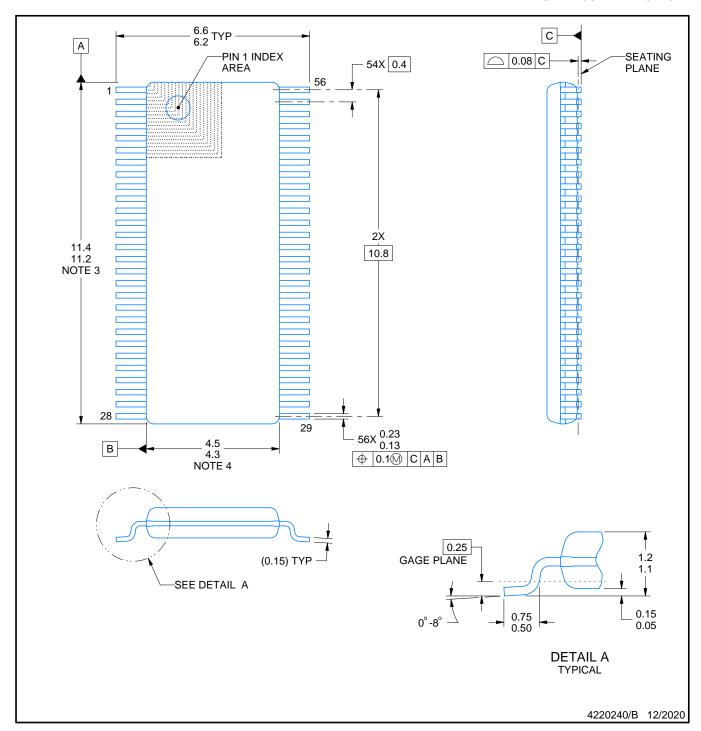
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





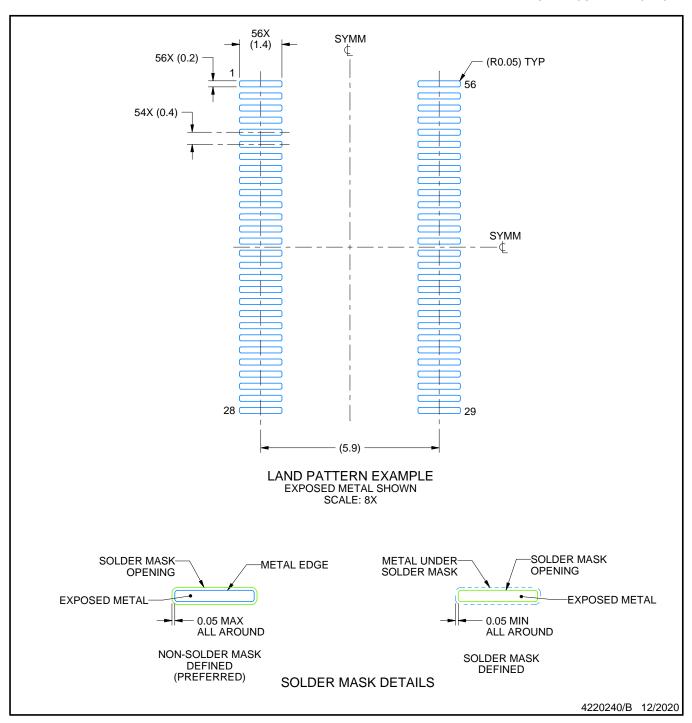
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-194.



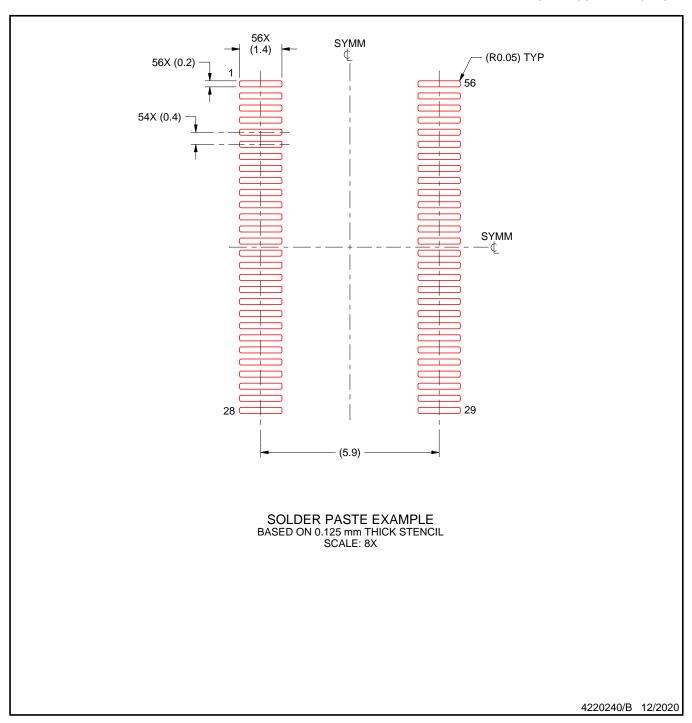


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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